

TRANSIL™ array for ESD protection

Main applications

Where transient overvoltage protection in ESD sensitive equipment is required, such as:

- Computers
- Printers
- Communication systems
- Cellular phone handsets and accessories
- Video equipment

Features

- 4 unidirectional TRANSIL diodes (ESDA6V1M6)
- 5 unidirectional TRANSIL diodes (ESDA6V1-5M6)
- Breakdown Voltage $V_{BR} = 6.1 \text{ V min}$
- High peak power dissipation: 100 Watts 8/20 μs
- Low leakage current < 500 nA
- Low diode capacitance (70 pF typ at 0 V)
- Very small PCB area: 1.45 mm²
- 500 microns pitch
- Leadfree package

Description

The ESDA6V1xxM6 is monolithic arrays designed to protect up to 4 or 5 lines against ESD transients.

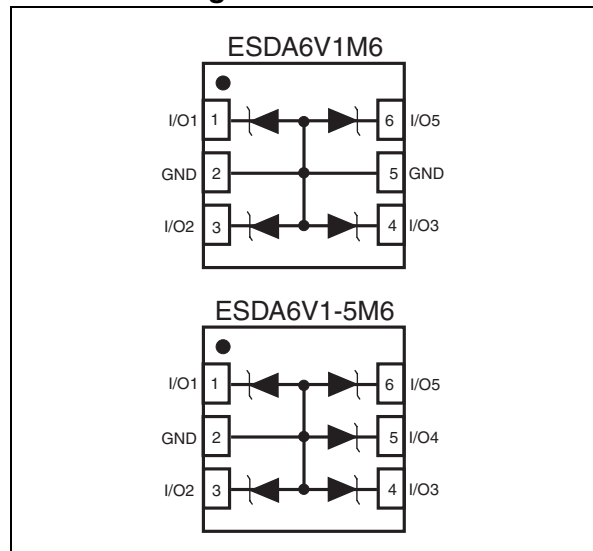
The device is ideal for applications where both reduced print circuit board space and power absorption capability are required.

Benefits

- High ESD protection level
- High integration
- Suitable for high density boards



Functional diagram



Order Code

Part number	Marking
ESDA6V1M6	I
ESDA6V1-5M6	J

Complies with the following standards:

IEC61000-4-2

15 kV (air discharge)

8 kV (contact discharge)

MIL STD 883E- Method 3015-7: class3

25 kV (human body model)

TM: TRANSIL is a trademark of STMicroelectronics

1 Characteristics

1.1 Absolute maximum ratings ($T_{amb} = 25\text{ °C}$)

Symbol	Parameter	Value	Unit
V_{PP}	ESD discharge – IEC61000-4-2 air discharge IEC61000-4-2 contact discharge	± 15 ± 8	kV
P_{PP}	Peak pulse power dissipation (8/20 μ s) ⁽¹⁾	T_j initial = T_{amb} 100	W
I_{pp}	Repetitive peak pulse current typical value (8/20 μ s)	8	A
T_j	Junction temperature	125	°C
T_{stg}	Storage temperature range	-55 + 150	°C
T_L	Maximum lead temperature for soldering during 10 s at 5 mm for case	260	°C
T_{OP}	Operating temperature range	-40 + 125	°C

1. For a surge greater than the maximum values, the diode will fail in short-circuit.

1.2 Electrical characteristics ($T_{amb} = 25\text{ °C}$)

Symbol	Parameter
V_{RM}	Stand-off voltage
V_{BR}	Breakdown voltage
V_{CL}	Clamping voltage
I_{RM}	Leakage current @ V_{RM}
I_{PP}	Peak pulse current
αT	Voltage temperature coefficient
V_F	Forward voltage drop

Parameter	Test Condition	Min	Typ	Max	Unit
V_{BR}	$I_R = 1\text{ mA}$	6.1		7.2	V
I_{RM}	$V_{RM} = 3\text{ V}$			500	nA
V_F	$I_F = 10\text{ mA}$			1	V
R_d			1		Ω
$\alpha T^{(1)}$	$I_R = 1\text{ mA}$			5	$10^{-4}/\text{°C}$
C	$V_R = 0\text{ V DC}$, $F = 1\text{ MHz}$, $V_{osc} = 30\text{ mV}_{RMS}$		70		pF

1. $\Delta V_{BR} = \alpha T * (T_{amb} - 25\text{ °C}) * V_{BR}(25\text{ °C})$

Figure 1. Relative variation of peak pulse power versus initial junction temperature

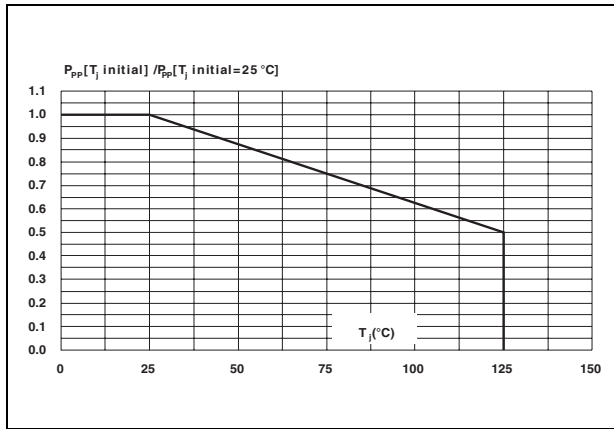


Figure 2. Peak pulse power versus exponential pulse duration

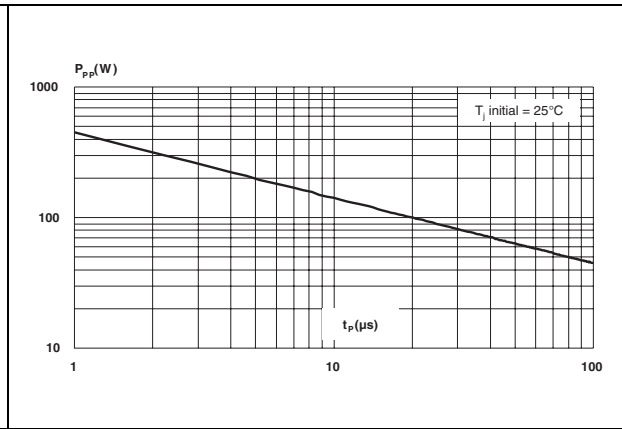


Figure 3. Clamping voltage versus peak pulse current (typical values, rectangular waveform)

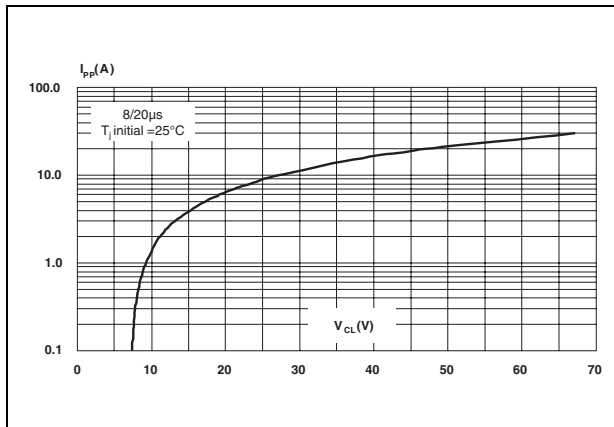


Figure 4. Forward voltage drop versus peak forward current (typical values)

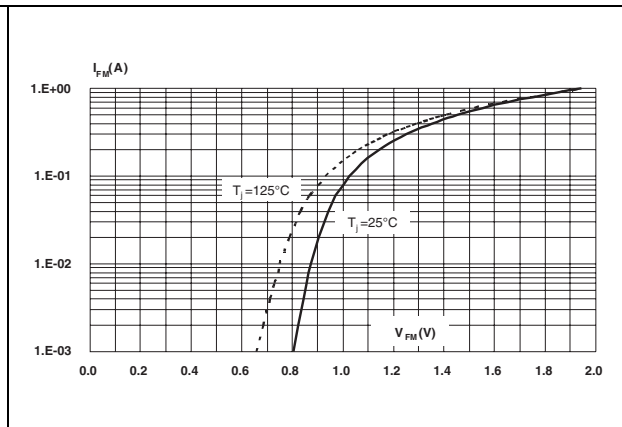


Figure 5. Junction capacitance versus reverse voltage applied (typical values)

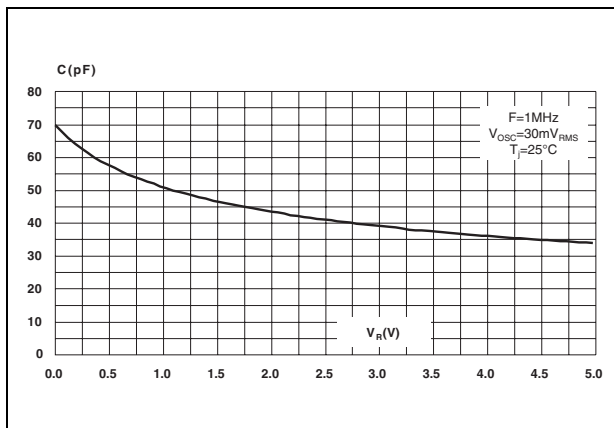


Figure 6. Relative variation of leakage current versus junction temperature (typical values)

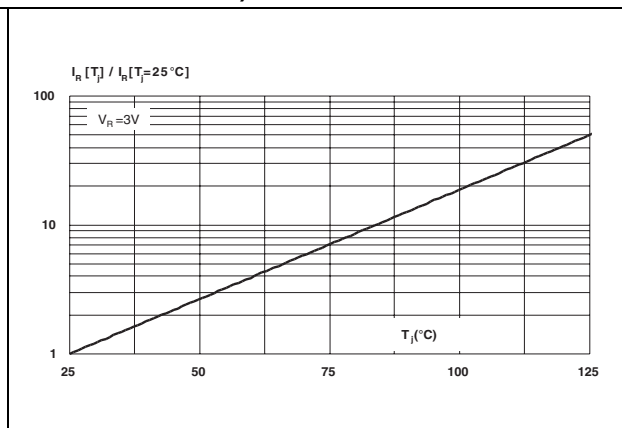


Figure 7. S21 attenuation measurement results of each channel

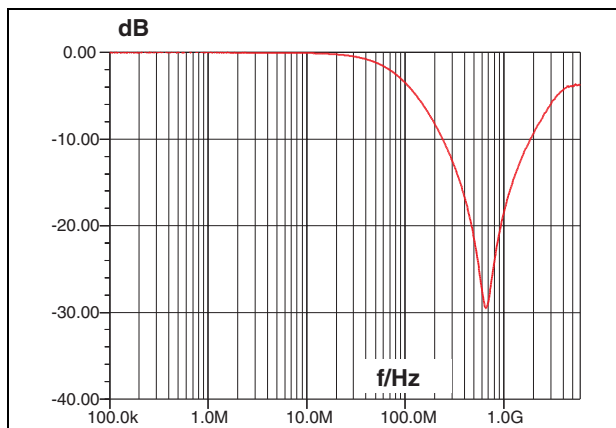


Figure 8. Analog crosstalk measurements between channels

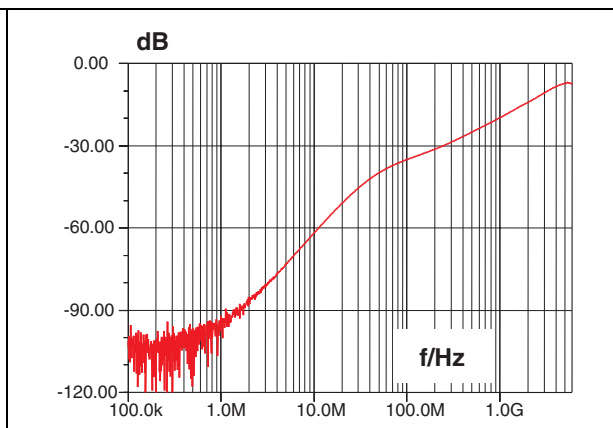


Figure 9. ESD response to IEC6100-4-2 (+15 kV air discharge) on each channel

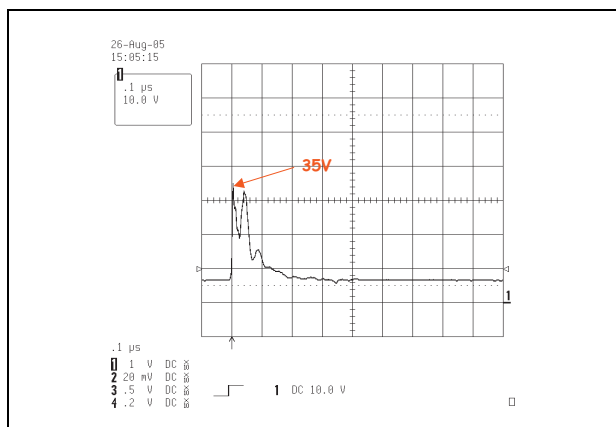
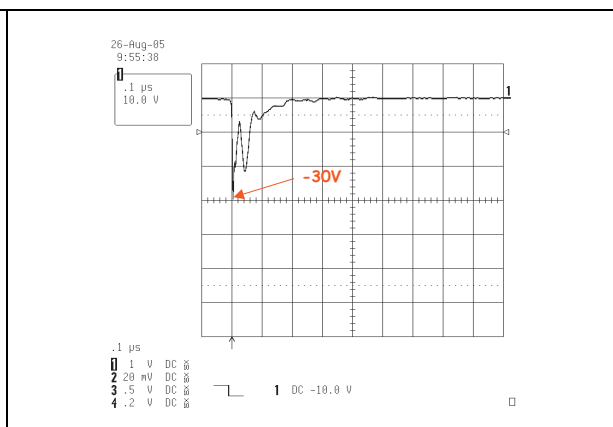
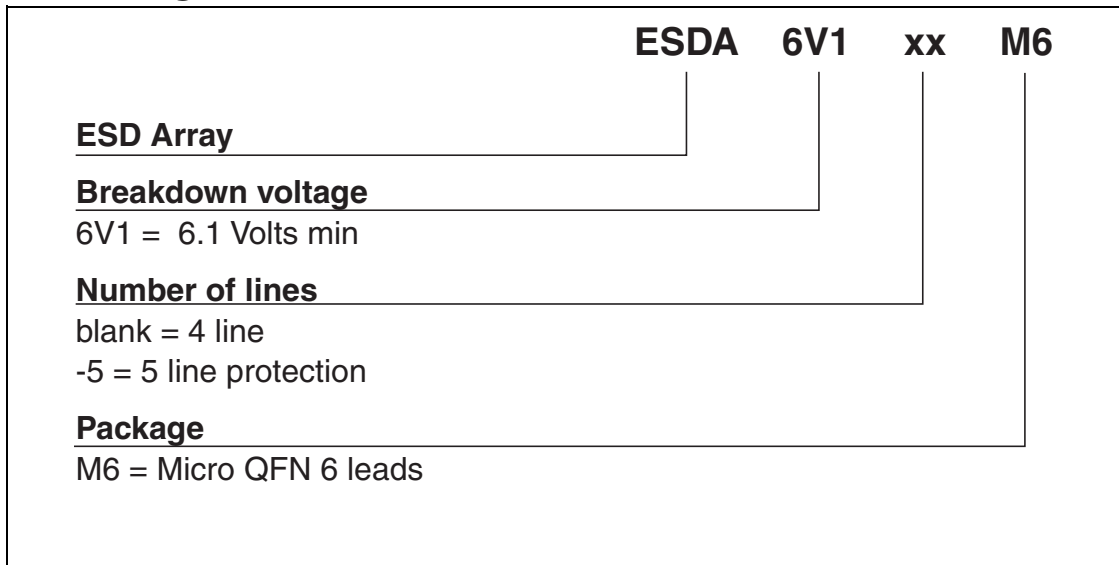


Figure 10. ESD response to IEC6100-4-2 (-15 kV air discharge) on each channel



2 Ordering information scheme



3 Package information

Table 1. Mechanical data

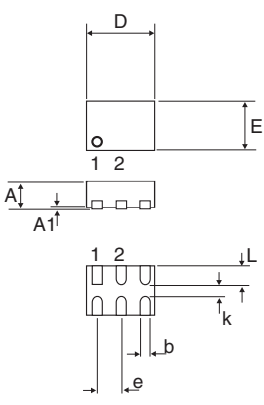
	DIMENSIONS						
	REF	Millimeters			Inches		
		Min	Typ	Max	Min	Typ	Max
	A	0.50	0.55	0.60	0.20	0.22	0.24
A1	0.00	0.02	0.05	0.00	0.01	0.02	
b	0.18	0.25	0.30	0.07	0.10	0.12	
D		1.45			0.57		
E		1.00			0.39		
e		0.50			0.20		
k	0.20			0.08			
L	0.30	0.35	0.40	0.12	0.14	0.16	

Figure 11. Footprint

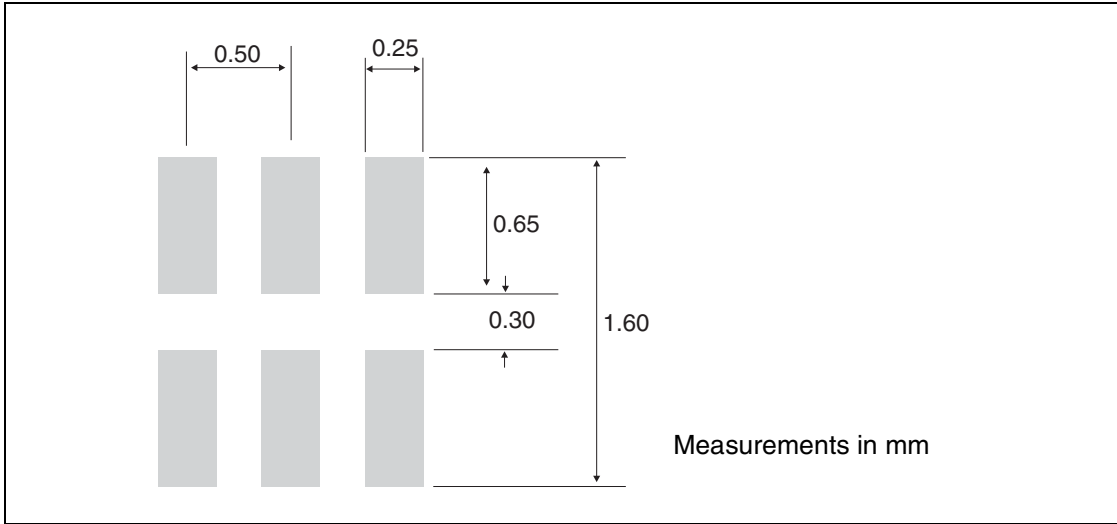
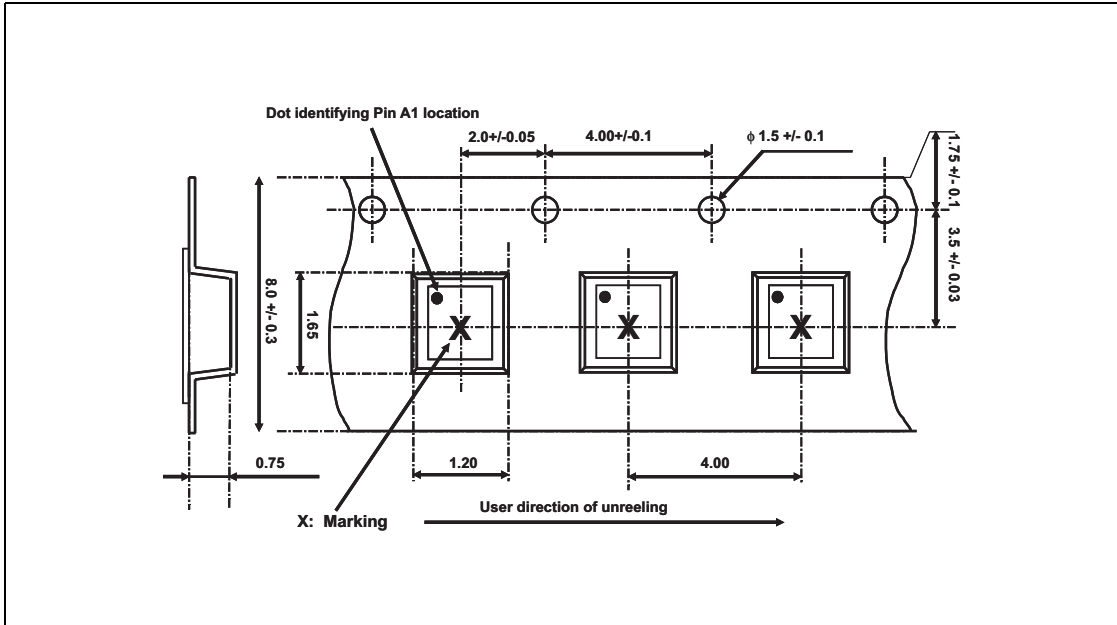


Figure 12. Tape and reel specification



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

4 Ordering information

Part number	Marking	Package	Weight	Base qty	Delivery mode
ESDA6V1M6	I	Micro QFN	2.2 mg	30,000	Tape and reel
ESDA6V1-5M6	J	Micro QFN	2.2 mg	30,000	Tape and reel

5 Revision history

Date	Revision	Changes
19-Sep-2005	1	Initial release.
10-Oct-2005	2	Package title changed from DFN to QFN. No technical changes.

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